

Application Specific Discretes A.S.D.™

#### FEATURES

- HIGH VOLTAGE BREAKOVER DIODE: V<sub>BO MIN</sub> = 195 or 215 V
- $\scriptstyle \bullet$  HIGH HOLDING CURRENT STRUCTURE :  $\rm I_{H}$  > 50 mA
- HIGH PEAK CURRENT PULSE CAPABILITY :  $I_{TRM} = 50 \text{ A}$
- DIRECT OPERATION ON 220/240 VAC MAINS CIRCUITS

#### BENEFITS

- SPACE SAVING THANKS TO MONOLOTHIC FUNCTION INTEGRATION
- HIGH RELIABILITY WITH PLANAR TECHNOLOGY

#### DESCRIPTION

The LIC01 has been especially designed for high voltage pulse generation circuits such as light ignitors for :

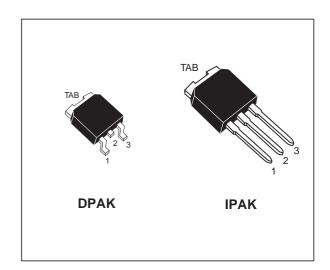
- . High pressure sodium lamp
- . Lamp flashing circuit
- . Metal Halid lamp

It uses a high performance planar diffused technology device suitable for high surge current operation in rugged environmental conditions.

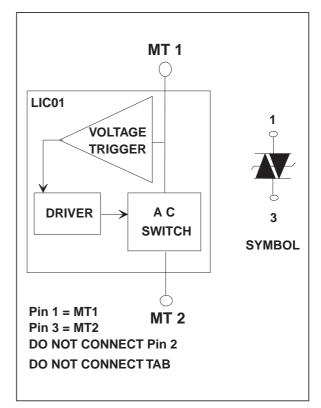
When the voltage across the device reaches the breakover voltage, it decreases from an off-state to low voltage on-state condition. When the current through the circuit drops below the holding current  $I_{\rm H}$ , the device comes back to the off-state.

DEVICE TYPE	BREAKDOWN VOLTAGE RANGE
LIC01-195	V <sub>BO</sub> min: 195V V <sub>BO</sub> max: 230V
LIC01-215	V <sub>BO</sub> min: 215V V <sub>BO</sub> max: 255V

# LIGHT IGNITION CIRCUIT



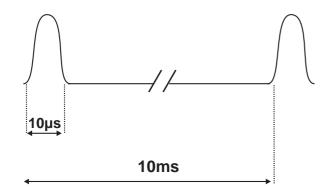
#### **FUNCTIONAL DIAGRAM**



# ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
I <sub>TRM</sub>	Repetitive surge peak on state current	±50	А
I <sub>T(RMS)</sub>	RMS on state current	1.2	А
di/dt	Critical rate of rise on state current	80	A/μs
V <sub>DRM</sub> / V <sub>RRM</sub>	Repetitive peak off state voltage	180	V
Tstg	Storage junction temperature range	- 40 to + 125	°C
Tj	Operating junction temperature range	-20 to 125	°C
TL	Maximum lead temperature for soldering during	260	°C

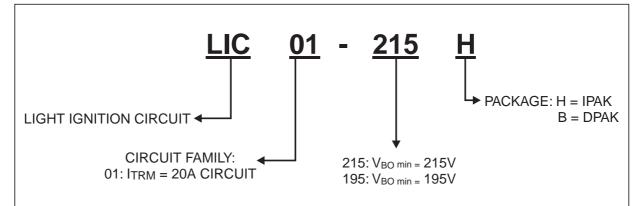
Note 1 : Test current waveform



# THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction to ambient	100	°C/W
Rth(j-c)	Junction to case	3.5	°C/W

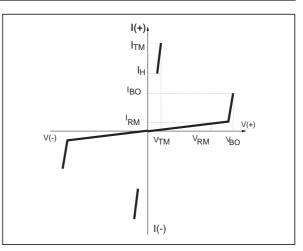
# **ORDERING INFORMATION**



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#### **ELECTRICAL CHARACTERISTICS**

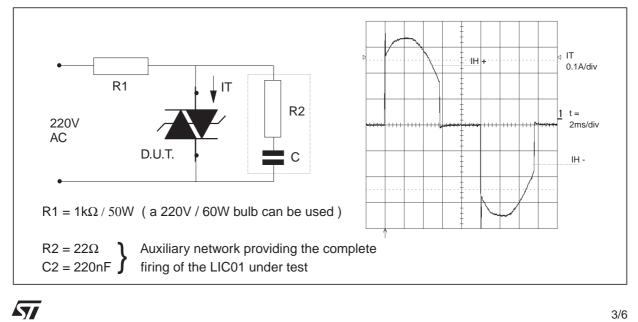
Symbol	Parameters			
V <sub>RM</sub>	Stand-off voltage			
V <sub>TM</sub>	On-state voltage			
V <sub>BO</sub>	Breakover voltage			
I <sub>TM</sub>	On-state current			
Ι <sub>Η</sub>	Holding current			
I <sub>BO</sub>	Breakover current			
I <sub>RM</sub>	A Leakage current			

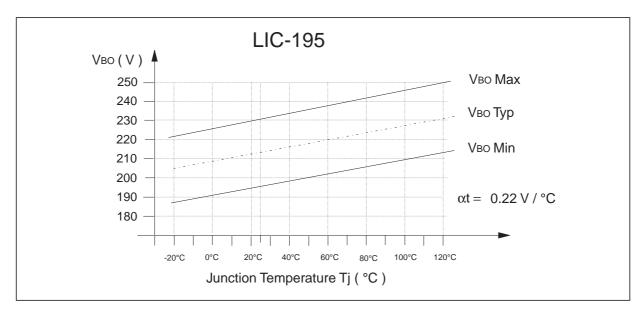


#### ELECTRICAL PARAMETERS

Symbol	Tes	Value	Unit			
I <sub>RM</sub>	V <sub>D</sub> = V <sub>RM</sub> 180V		Tj = 25°C	MAX	5	μA
			Tj = 125°C	MAX	50	μA
V <sub>BO</sub>	I <sub>BO</sub>	LIC01-195	Tj = 25°C	MIN	195	V
				MAX	230	
		LIC01-215	Tj = 25°C	MIN	215	V
				MAX	255	
I <sub>BO</sub>	V <sub>BO</sub> max.		Tj = 25°C	TYP	200	μA
				MAX	500	
I <sub>H</sub>	I <sub>T</sub> = 350mA		Tj = 25°C	MIN	50	mA
V <sub>TM</sub>	I <sub>TM</sub> = 1A		Tj = 25°C	MAX	5	V

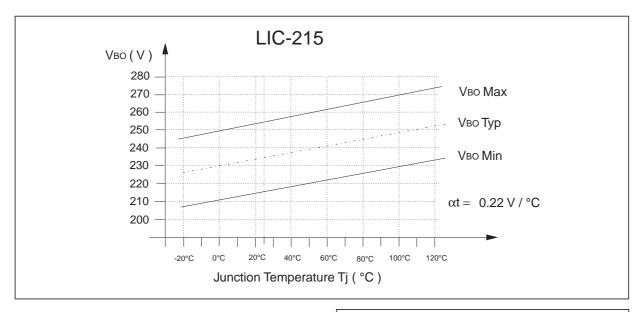
# HOLDING CURRENT TEST CIRCUIT





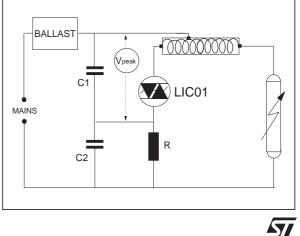
#### **VARIATION OF VBO VERSUS JUNCTION TEMPERATURE**





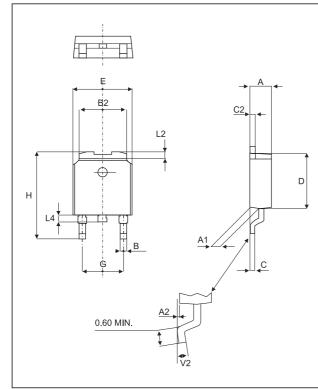
#### **TYPICAL APPLICATION**

When the peak voltage across C1 reaches the break over voltage VBO of the LIC01, this device turns on and produces a pulse of current through the primary of the transformer. In turn, the transformer generates high voltage pulses across the lamp.



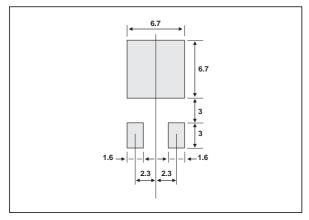
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# PACKAGE MECHANICAL DATA DPAK (Plastic)



	DIMENSIONS						
REF.	Millimeters			Inches			
	Min.	Тур.	Max	Min.	Тур.	Max.	
А	2.20		2.40	0.086		0.094	
A1	0.90		1.10	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.90	0.025		0.035	
B2	5.20		5.40	0.204		0.212	
С	0.45		0.60	0.017		0.023	
C2	0.48		0.60	0.018		0.023	
D	6.00		6.20	0.236		0.244	
Е	6.40		6.60	0.251		0.259	
G	4.40		4.60	0.173		0.181	
Н	9.35		10.10	0.368		0.397	
L2		0.80			0.031		
L4	0.60		1.00	0.023		0.039	
V2	0°		8°	0°		8°	

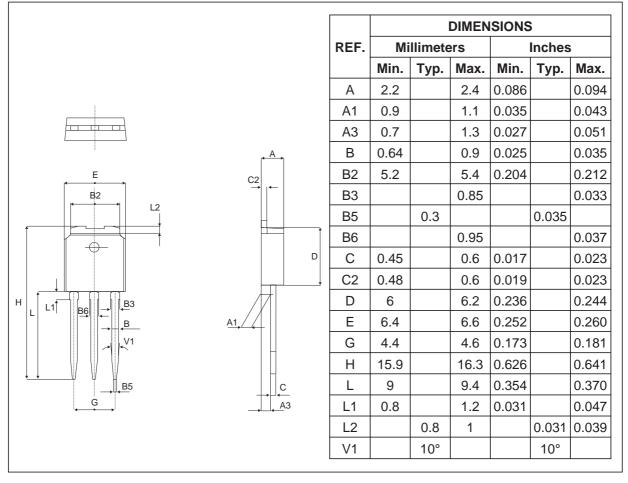
# FOOT PRINT DIMENSIONS (in millimeters)



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#### PACKAGE MECHANICAL DATA

**IPAK** (Plastic)



#### **OTHER INFORMATION**

Туре	Marking	Package	Weight	Base qty	Delivery mode
LIC01-xxxH	LIC01-xxxH	IPAK	0.4 g	75	Tube
LIC01-xxxB	LIC01-xxxB	DPAK	0.3 g	75	Tube

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